

Product data sheet

1. General description

Ultrafast power diode in 2-leads TO-262 (I2PAK) plastic package.

2. Features and benefits

- Low forward voltage drop
- Low leakage current
- Soft reverse recovery characteristics
- High thermal cycling performance

3. Applications

- Home appliance power supply
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Quick referen	ice data	
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Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	00		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 150 °C; Fig. 1; Fig. 2; Fig. 3			9		A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 150 °C; square-wave pulse	18		A		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	120 132			A	
		t_{p} = 8.3 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse;			А		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.05	1.3	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	0.9	1.1	V
Dynamic	characteristics						
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	40	75	ns

5. Pinning information

Table 2. F	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	К	cathode		K — A 001aaa020				
2	А	anode		001888020				
mb	mb	mounting base; connected to cathod	K A TO262 2L (I2PAK)					

6. Ordering information

able 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BYV29G-600P	TO-262	Plastic single-ended package(I2PAK); 2 leads TO-262	I2PAK			

7. Marking

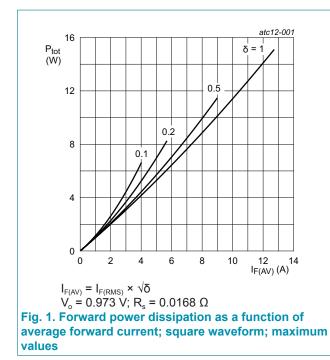
Table 4. Marking codes							
	Type number	Marking codes					
	BYV29G-600P	BYV29G-600P					

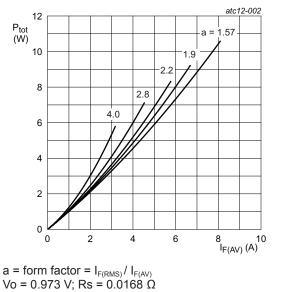
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

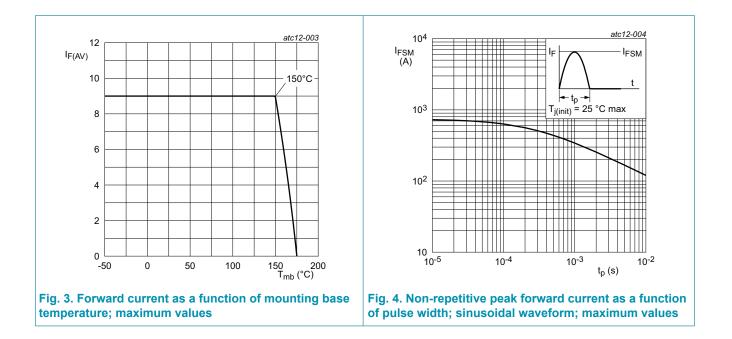
Symbol	Parameter	Conditions	Values	Unit
V _{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V _R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 150 °C; Fig. 1; Fig. 2; Fig. 3	9	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 150 °C; square-wave pulse	18	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	120	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	132	А
T _{stg}	storage temperature		-55 to 175	°C
Tj	junction temperature		175	°C





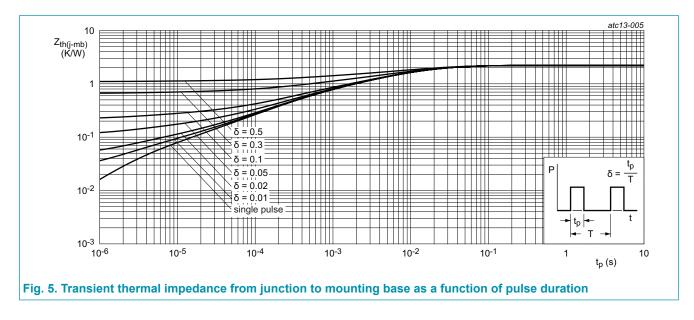
Vo = 0.973 V; Rs = 0.0168 Ω Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

BYV29G-600P Ultrafast power diode



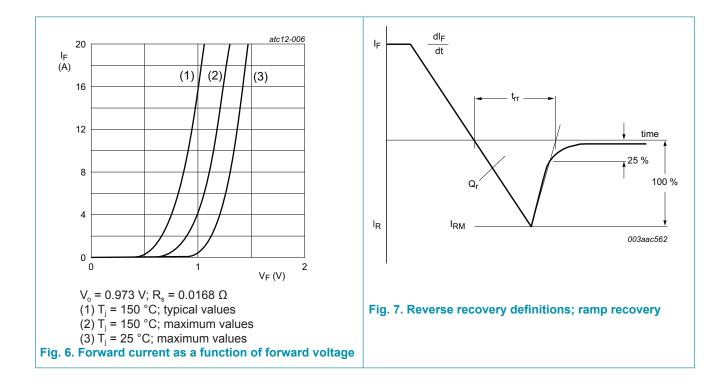
9. Thermal characteristics

Table 6. Th	ermal characteristics		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	2.2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W

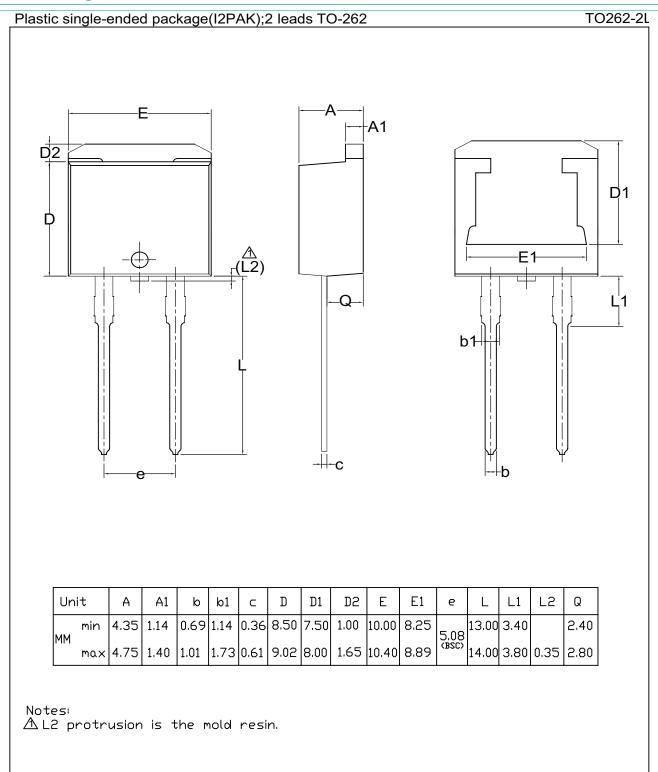


10. Characteristics

Table 7. Cl	naracteristics						
Symbol	Parameter	Conditions	M	in	Тур	Max	Unit
Static cha	racteristics						
$V_{\rm F}$	forward current	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>	-		1.05	1.3	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>	-		0.9	1.1	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-		-	10	μA
		V _R = 600 V; T _j = 150 °C	-		-	0.4	mA
Dynamic	characteristics						
Q _r	reverse charge	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-		55	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-		40	75	ns
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-		1.9	-	A
		$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-		2.8	-	A



11. Package outline



BYV29G-600P

Ultrafast power diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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